

PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
INPUT					
Reverse voltage			V <sub>R</sub>	6	V
Forward current			I <sub>F</sub>	20	mA
Surge forward current			I <sub>FSM</sub>	1.5	Α
Power dissipation	t ≤ 10 μs		P <sub>diss</sub>	30	mW
ОUТРUТ					
Repetitive peak off-state voltage		BRT11	V <sub>DRM</sub>	400	V
		BRT12	$V_{DRM}$	600	V
		BRT13	$V_{DRM}$	800	V
RMS on-state current			I <sub>TRMS</sub>	300	mA
Single cycle surge current	50 Hz		I <sub>TSM</sub>	3	Α
Power dissipation			P <sub>diss</sub>	600	mW
COUPLER					
Maximum power dissipation			P <sub>tot</sub>	630	mW
Isolation test voltage (between emitter and detector, climate per DIN 500414, part 2, Nov. 74) (1)			V <sub>ISO</sub>	5300	$V_{RMS}$
Reference voltage in accordance with VDE 0110 b			V <sub>ref</sub>	500	V <sub>RMS</sub>
Reference voltage in accordance with VDE 0110 b (insulation group C)			V <sub>ref</sub>	600	$V_{DC}$
Creepage distance				≥ 7.2	mm
Clearance distance				≥ 7.2	mm
Comparative tracking index per DIN IEC 112/VDE 0303 part 1	group IIIa according to DIN VDE 0109		СТІ	≥ 175	
Indiation variations	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C		R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C		R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Storage temperature range			T <sub>stg</sub>	- 40 to + 150	°C
Ambient temperature range			T <sub>amb</sub>	- 40 to + 100	°C

#### Notes

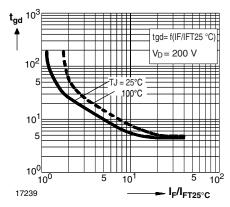
Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Test AC voltage in accordance with DIN 57883, June 1980.

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)										
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT			
INPUT			•				•			
Forward voltage	I <sub>F</sub> = 10 mA		$V_{F}$		1.1	1.35	V			
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>			10	μA			
Thermal resistance, junction to ambient (1)			R <sub>thJA</sub>			750	°C/W			
OUTPUT										
Peak off-state voltage	I <sub>D(RMS)</sub> = 100 μA	BRT11	V <sub>DM</sub>		400		μA			
		BRT12			600		μA			
		BRT13			800		μA			
Off-state current	$T_C = 80  ^{\circ}C,  V_{DRM}$		$I_{D}$		0.5	100	μΑ			
On-state voltage	$I_T = 300 \text{ mA}$		$V_{T}$			2.3	V			
Pulse current	$t_p \le 5 \ \mu s, \ f = 100 \ Hz, \ dl_{tp}/dt \le 8 \ A/\mu s$		I <sub>tp</sub>			2	Α			
Critical rate of rise of off-state voltage	$V_D = 0.67 \ V_{DRM}, \ T_j = 25 \ ^{\circ}C$		dV/dt <sub>cr</sub>	10			kV/μs			
	$V_D = 0.67 \ V_{DRM}, \ T_j = 80 \ ^{\circ}C$		dV/dt <sub>cr</sub>	5			kV/μs			
Critical rate of rise of voltage at current commutation	$V_D = 0.67 V_{DRM}, T_j = 25 ^{\circ}C,$ $dI/dt_{crq} \le 15  A/ms$		dV/dt <sub>crq</sub>	10			kV/μs			
	$V_D = 0.67 \ V_{DRM}, \ T_j = 80 \ ^{\circ}C,$ $dI/dt_{crq} \leq 15 \ A/ms$		dV/dt <sub>crq</sub>	5			kV/μs			
Critical rate of rise of on-state at current			dl/dt <sub>cr</sub>	8			A/µs			
Holding current	V <sub>D</sub> = 10 V		I <sub>H</sub>		80	500	μA			
Thermal resistance, junction to ambient			R <sub>thJA</sub>			125	°C/W			
COUPLER										
Trigger current	$V_D = 10 \text{ V}, \text{ F - versions}$		I <sub>FT</sub>			1.2	mA			
	V <sub>D</sub> = 10 V, H - versions		I <sub>FT</sub>	0.4		2	mA			
	V <sub>D</sub> = 10 V, M - versions		I <sub>FT</sub>	0.8		3	mA			
Trigger current temperature gradient			$\Delta I_{FT}/\Delta T_{j}$		7	14	μΑ/°C			
Capacitance (input to output)	f = 1 MHz, V <sub>R</sub> = 0 V		C <sub>IO</sub>			2	pF			

#### **Notes**

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)





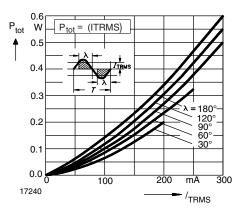


Fig. 2 - Power Dissipation 60 Hz to 60 Hz Line Operation

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<sup>•</sup> Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

<sup>(1)</sup> Static air, SITAC soldered in PCB or base plate.

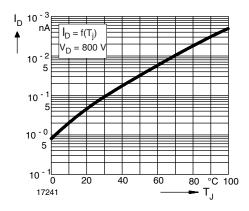


Fig. 3 - Typical Off-State Current

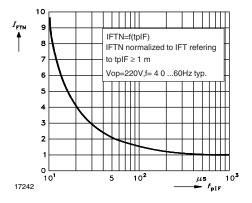


Fig. 4 - Pulse Trigger Current

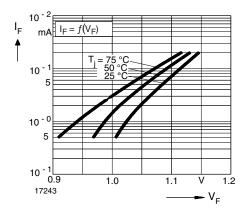


Fig. 5 - Typical Input Characteristics

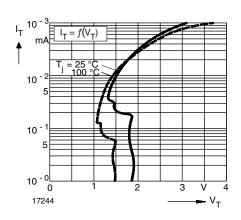


Fig. 6 - Typical Output Characteristics

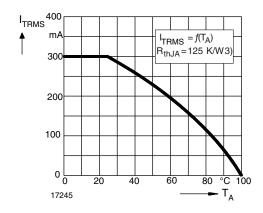


Fig. 7 - Current Reduction

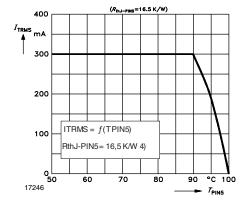
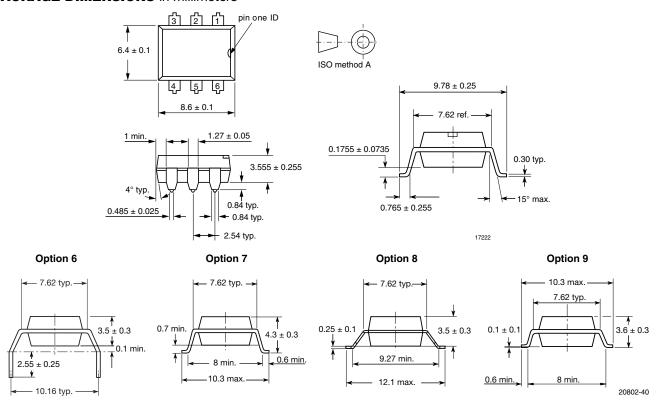


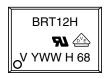
Fig. 8 - Current Reduction



#### **PACKAGE DIMENSIONS** in millimeters



### **PACKAGE MARKING** (example)



#### Notes

- Only options 1, and 7 are reflected in the package marking.
- The VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.

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